NSN 5961-01-449-6075

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-449-6075 **Inclosure Material:** Glass **Overall Length:** 1.050 inches **Overall Diameter:** 1.900 inches **Mounting Facility Quantity: Mounting Method:** Threaded hole Thready Qty Per Inch (tpi): 28 **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 10000.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 1.20 amperes forward current, average **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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